	L #	Hits	Search Text	DBs	Time Stamp
1	L1	8146	(427/2.1-2.31,488-491,535-539,562-564,569-579).CCLS.	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:09
2	L2	3975	((plasma (glow electric corona)adj discharg\$4)with(atmos pheric adj pressure "1 atm" "1 atmosphere" "736 torr" "736 mm Hg" atm))	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:15
3	L3	300	1 and 2	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:09
4	L4	2211	(427/2.1-2.31).CCLS.	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:09

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	L #	Hits	Search Text	DBs	Time Stamp
5	L5	45	3 and (cell protein peptide amino adj acid P15 "P-15" cadherin)	USPA T; US-P GPUB; PO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:15
6	L6	1197	4 and (cell protein peptide amino adj acid P15 "P-15" cadherin)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:16
7	L7	681	4 and (plasma (glow electric corona) adj discharg\$4)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:16
8	L8	519	7 and (cell protein peptide amino adj acid P15 "P-15" cadherin)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:17

	L #	Hits	Search Text	DBs	Time Stamp
9	L9	4	3 and (laminin fibronectin collagrn vitronectin tenascin fibrinogen thrombospondin osteopontin von adj willibrand adj factor sialoprotein)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:20
10	L10	148	7 and (laminin fibronectin collagrn vitronectin tenascin fibrinogen thrombospondin osteopontin von adj willibrand adj factor sialoprotein)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:21
11	L11	147	7 and (collagen)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:21
12	L12	4	3 and (collagen)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:22

	L #	Hits	Search Text	DBs	Time Stamp
13	L13	3	12 and 9	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:22
14	L14	5	12 or 9	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:24
15	L15	211	10 or 11		2003/06/2 4 15:23
16	L16	84	10 and 11	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:23

	L #	Hits	Search Text	DBs	Time Stamp
17	L17	45	12 or 9 or 5	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:24
18	L18	5	12 or 9 and 5	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:24
19	L19	40	17 not 18	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/06/2 4 15:25

To LZOCO 19 + (PTFE as polytetra fluoroethylm or ....)

. 10	1		Document	Issue	Title	Current	Inventor	
1 10			ID	Date	Title	· OR	Inventor	
	Th	1	US 2003011 3478 A1	2003061 9	Surface coating method and coated device	427/535	Dang, Mai Huong et al.	app
	1/12/20	2	US \$45-0 2003000 8397 A1 [0012]	edity pla	s smc at la		Beumer, Gerrit Jan et al. [coz]	Foxog Jall adher cottage, fibered vitrimos, lame
pull type		15) Fis 163 1. By 1	131H filmos US 6131580 Afin filmos Infin filmos	2000101 7 rech, vitar	Templat e imprint ed materia ls by RFGD plasma deposit	128/898	Ratner, Buddy D. et al.	
	1 (77)	DI 10 77	144 FSW 71.	Vian Me L	10d- 1	1) mtore.	tomate & bu	to lake
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	*	5	US 5364662 A	1994111 5	Surface treatme nt of silicon e rubber	427/536	Domenic o, Edward D. et al.	
	Ab	- Silic	en Vulsken enaph	- plana Curalut	resterio	#2 4 N2	or He I Ne ,	Ar (6-fre)
		1An		eract t	250-34			back to late

		Document	t e	Title	Current	Inventor
9		ID	Date		OR	Invencor
	1	US 2003008 2412 A1	2003050 1	Method for forming thin film, article having thin film, optical film, dielect ric coated electro de, and plasma dischar ge process or	428/697	Fukuda, Kazuhir o et al.
(JO)		US 2003007 2891 A1	1	Thin film forming method, optical film, polarizing film and image display method	427/569	Murakam i, Takashi et al.
	3/	US 1 fo 2002017 6946 A1 Open c	1 4/10/01 2002112 8 ···	Porous plasma tr <u>ea</u> ted sheet materia l	427/569	O'Brien , Jeffrey J.
	4		<b>_</b>		427/569	O'Brien , Jeffrey J.

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		Document ID	Issue Date	Title	Current OR	Inventor
	*	US 2002016 8466 A1	4	System and process for solid-s tate deposit ion and consoli dation of high velocit y powder particl es using thermal plastic deforma tion	427/180	Tapphor n, Ralph M. et al.
LW	6	US 2002012 2896 A1	2002090 5	Capilla ry dischar ge plasma apparat us and method for surface treatme nt using the same	427/569	Kim, Steven et al.
~~~	7	US 2002010 6500 A1	2002080 8	Plasma curing process for porous low-k materia	428/304 .4	Albano, Ralph et al.

	Document ID	Issue Date	Title	Current OR	Inventor
8	US 6583064 B2	2003062 4 M W	Low contami nation high density plasma etch chamber s and methods for making the same	438/710	Wicker, Thomas E. et al.
9	US 6548123 B1	2003041 5	Method for coating a plastic contain er with vacuum vapor deposit ion	427/566	Plester , George et al.
10	US 6472076 B1	9	Deposit ion of organos ilsesquioxane films	428/447	Hacker, Nigel P.

	Document ID	Issue Date	Title	Current OR	Inventor
	US 6417071 B2	2002070	Sub-atm ospheri c pressur e thermal chemica l vapor deposit ion (SACVD) trench isolati on method with attenua ted surface sensiti vity	438/424	Jang, Syun-Mi ng
12	US 6403490 B1	2002061	Method of produci ng a plasma by capacit ive-typ e dischar ges with a multipo le barrier , and apparat us for impleme nting such a method		Lagarde , Thierry et al.

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		Document ID	Issue Date	Title	Current OR	Inventor
120	13	US 6159531 A	2000121	Coating having biologi cal activit y and medical implant having surface carryin g the same and method	427/2 <b>.</b> 2 4	Dang, Mai Huong et al.
	14	US 6130397 A	2000101 0	Thermal plasma anneali ng system, and anneali ng process	219/121 .37	Arai, Michio
•	15	US 5993917 A	1999113 0 V	Method and apparat us for improvi ng wettabi lity of foam	427/536	Pan, Alfred I-Tsung et al.
	16	US 5968611 A	1999101	Silicon nitroge n-based films and method of making the same	427/579	Kaloyer os, Alain E. et al.

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		Document ID	Issue Date	Title	Current OR	Inventor
L20)	17	US 5843789 A	1998120 1	Method of analysi s of genomic biopoly mer and porous' materia ls for genomic analyse s		Nomura, Hiroshi et al.
	18	US 5616368 A	1997040 1	Field emissio n devices employi ng activat ed diamond particl e emitter s and methods for making same	427/535	Jin, Sungho et al.
	<b>1</b> 9	US 5587207 A	1996122 4	Arc assiste d CVD coating and sinteri ng method	427/571	Gorokho vsky, Vladimi r I.

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	Document ID	Issue Date	Title	Current OR	Inventor
20	`US 5547716 A	1996082 0	Laser absorpt ion wave deposit ion process and apparat us	427/577	Thaler, Stephen L.
21	US 5510151 A	1996042	Continu ous film-fo rming process using microwa ve energy in a moving substra te web functio ning as a substra te and plasma generat ing space	427/509	Matsuya ma, Jinsho et al.
22	US 5470784 A	1995112	Method of forming semicon ducting materia ls and barrier s using a multipl e chamber arrange ment	438/61	Coleman , John H.

	Document	Issue Date	Title	Current OR	Inventor
23	US 5441765 A	1995081 5 Jac	Method of forming Si-O contain ing coating s	427/228	Ballanc e, David S. et al.
2,A	US 5409743 A	1995042 5	PECVD process for forming BPSG with low flow tempera ture	427/579	Bouffar d, Mark D. et al.
28	US 5366770 A	1994112 2	Aerosol -plasma deposit ion of films for electro nic cells	505/477	Wang, Xingwu
2.6	US 5324553 A	1994062 8	Method for the improve d microwa ve deposit ion of thin films	427/571	Ovshins ky, Stanfor d R. et al.
	US 5260105 A	1993110 9	Aerosol -plasma deposit ion of films for electro chemica l cells	427/576	Wang, Xingwu

		Document		Title	Current	Inventor
		ID	Date	11016	OR	Invencor
	28	A	1993030 9	microwa ve plasma chemica l vapor deposit ion method	438/479	Kawakam i, Soichir o et al.
pull )	136 A 129 139 H	wohstale paces of US143748 Aprosof Jus. Navla	mas laks 1992090 1 dlow h	Timber surface improvi ng treatme nt process	427/569	Ishikaw a, Hiroyuk i et al.
	<b>3</b> 0	US	1991052 1	Silicon thin film	.1 .1	Iijima, Shigeru et al.

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		Document ID	Issue Date	Title	Current OR	Inventor
	<b>)</b> 81	US 4792460 A	1988122	Method for product ion of polysil anes and polyger manes, and deposit ion of hydroge nated amorpho us silicon , alloys thereof , or hydroge nated amorpho us germani um	427/563	Chu, Ting L. et al.
1.H)/	82	US 4743258 A	1988051 0	Polymer materia ls for vascula r prosthe ses	623/1.4 9	Ikada, Yoshito et al.
	3,8	ÚS 4537795 A	1985082 7	Method for introdu cing sweep gases into a glow dischar ge deposit ion apparat us		Nath, Prem et al.

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		ID	Date	Title	OR	Inventor
	34	赵S 4527007 A	1985070 2	Process for forming passiva tion film on photoel ectric convers ion device and the device produce d thereby	136/256	Fuse, Mario
	35	US 4485121 A	1984112 7	Method for produci ng a fluorin e-conta ining amorpho us semicon ductor		Matsumu ra, Hideki
	36	US 4481229 A	1984110 6	Method for growing silicon -includ ing film by employi ng plasma deposit ion	427/571	Suzuki, Keizo et al.
	37	ÚS 4439463 A	1984032 7	Plasma assiste d deposit ion system	427/563	Miller, Stephen C.

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	Document ID	Issue Date	Title	Current OR	Inventor
38	US 4382099 A	1983050 3	Dopant predepo sition from high pressur e plasma source	438/57	Legge, Ronald N. et al.
	US 4226898 A	1980100 7	Amorpho us semicon ductors equival ent to crystal line semicon ductors produce d by a glow dischar ge process		Ovshins ky, Stanfor d R. et al.
	US 4226897 A		Method of forming semicon ducting materia ls and barrier s	438/96	Coleman , John H.

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			Document ID	Issue Date	Title	Current OR	Inventor	
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Die	-	(Br)	US 5843789 A Michel Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Miller Mil	aan)	materia ls for	,		
		(P8)	Mat. Santell	formod.	analyse	oumters.	• 6 . 4	t) to lah
		Kinı	V	Ū	Polymer materia		,	
	*	6	US 4743258 A	1988051 0	r	623/1.4 9	Ikada, Yoshito et al.	
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<del>20</del> )		Document ID	Issue Date	Title	Current OR	Inventor
		US 2003007 2891 A1 PTFE gbeh	: ¬	Thin film forming method, optical film, polarizing film and image display method	427/569	Murakam i, Takashi et al.
2		2896 A1	2002090 5	us and method for surface treatme nt using the same	427/569	Kim, Steven et al.
X 3	[OUI	7 Jub 115 Lo 7 philos US 2002010 6500 A1	8	Plasma curing process for porous low-k materia		Albano, Ralph et al.
pull 7 4		us 6159531 A		Coating having biologi cal activit y and medical implant having surface carryin g the same and method	427/2.2	Dang, Mai Huong et al.